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GODDARD SPACE FLIGHT CENTER

Test Lab Report Summary

Q10167DPA Project: Report Number: **SWIFT** Part Type: Microcircuit System: **BAT** Part Number: OP293ES *Initiated Date:* 05/01/2001 Date Code: Report Date: 0021 07/10/2001

Manufacturer:Analog DevicesInvestigator:C. Greenwell (562)Generic Number:OP293Requester:B. Meinhold (562)

Purchase Spec: Commercial Approval / Date:

Step 1: INCOMING INSPECTION

Test	Quantity	<u>Passed</u>	<u>Failed</u>
External Visual	N/A	N/A	N/A
PIND Condition A	N/A	N/A	N/A

Step 2: DESTRUCTIVE PHYSICAL ANALYSIS

Destructive Physical Analysis (DPA) was conducted per GSFC document "Plastic Encapsulated Microcircuit (PEM) Guidelines for Screening and Qualification for Space Applications", except that cross-section was done without dye penetrant and glassivation integrity testing was not performed.

No rejectable defects or anomalies were observed during this analysis.

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Part No:

Date Code: 0021

Α

A

OP293ES

GODDARD SPACE FLIGHT CENTER

Part Type: Manufacturer: Microcircuit

Analog Devices

Summary of Analysis: Serial Number G05 G07 H01 H05 H07 External Examination 1. Markings - legibility and correctness _____ Α Α A Α Α 2. Integrity of package seals N/A N/A N/A N/A N/A 3. Condition of external leads and plating _____ Α Α Α Α Α 4. Overall package condition Α Α Α A A

Radiographic Examination 5. Die bonding material and die alignment

5. Die bonding material and die angriment	Α	Α	Α	Α	Α	
6. Package seal integrity	N/A	N/A	N/A	N/A	N/A	
7. Presence of foreign material	A	Α	Α	Α	Α	
8. Lead dress (if revealed)	A	A	A	A	A	

Acoustic Microscopy Inspection

9. Condition of material interfaces (delaminations)	A	A	A	Α	A
10. Condition of molding material (voids, cracks)	A	A	A	A	A

Internal Examination (including cross-section)

11. Presence of foreign material

12. Mechanical condition of die	A	Α	A	A	A
13. Wire bonds and lead dress	N/P	N/P	A	A	A
14. Die bonding material	A	A	A	A	A
15. Condition of die surface	N/P	N/P	A	A	A
16. Condition of metallization	N/P	N/P	A	A	A
17. SEM Examination	N/P	N/P	A	A	A

Bond Strength

18. Strength	N/P	N/P	Α	Α	Α
19. Metallization adherence	N/P	N/P	A	A	A

Die Bond Strength

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20. Strength	N/P	N/P	N/P	N/P	N/P

SN's G05 and G07 subjected to cross-sectional examination.

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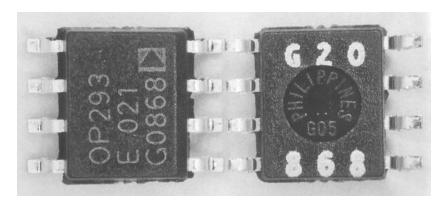


Figure 1. External top and bottom views of the OP293ES devices. Each device had a unique two or three character alphanumeric code that was used for reference designations during this analysis. 6X

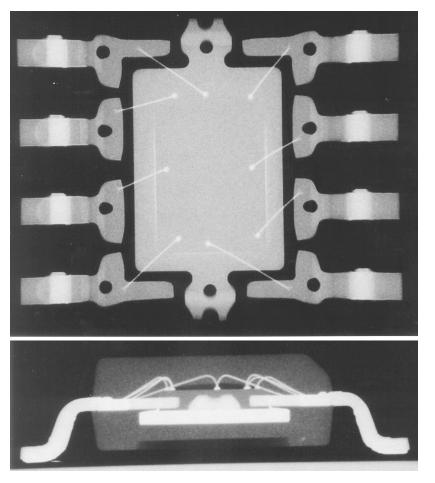


Figure 2. Top and side view radiographic images. Note the die coat visible in the side view image (dark area over the die). 16X

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Manufacturer: Analog Devices Date Code: 0021

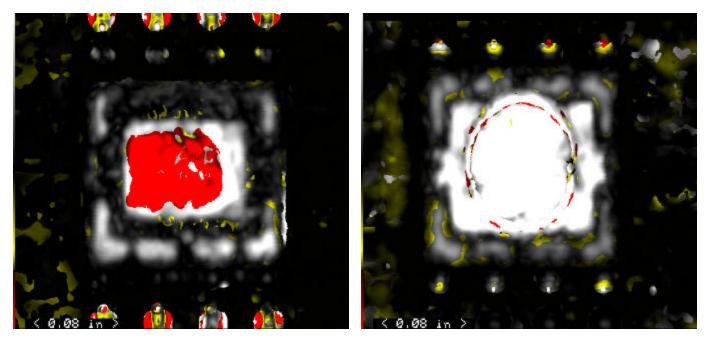


Figure 3. Top (left) and bottom C-SAM images of SN G05. The red area in the topside view is produced by the glob-top coating on the die.

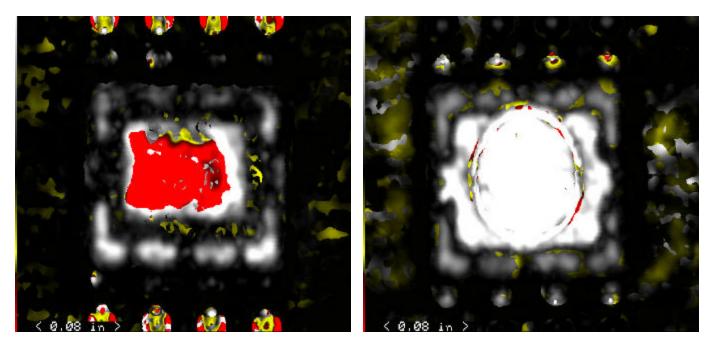


Figure 4. Top (left) and bottom C-SAM images of SN G07.

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Manufacturer: Analog Devices Date Code: 0021

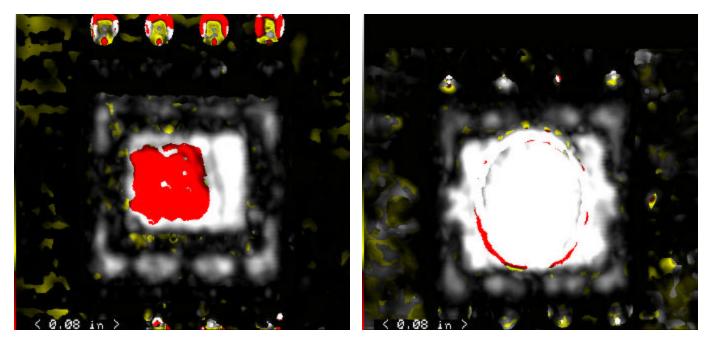


Figure 5. Top (left) and bottom C-SAM images of SN H01.

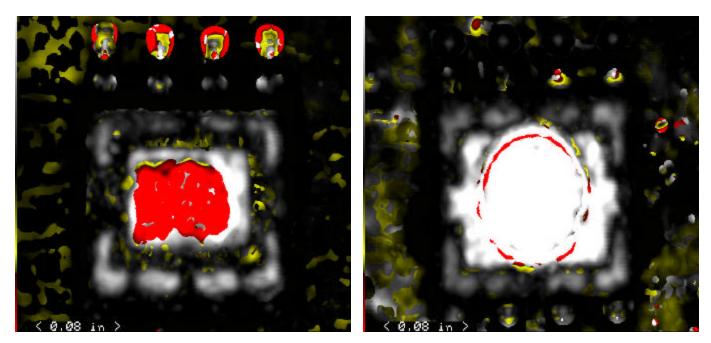


Figure 6. Top (left) and bottom C-SAM images of SN H05.

Part Type: Microcircuit Part No: OP293ES

Manufacturer: Analog Devices Date Code: 0021

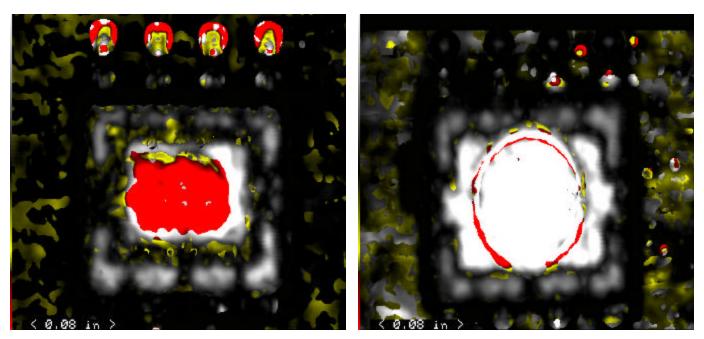


Figure 7. Top (left) and bottom C-SAM images of SN H07.

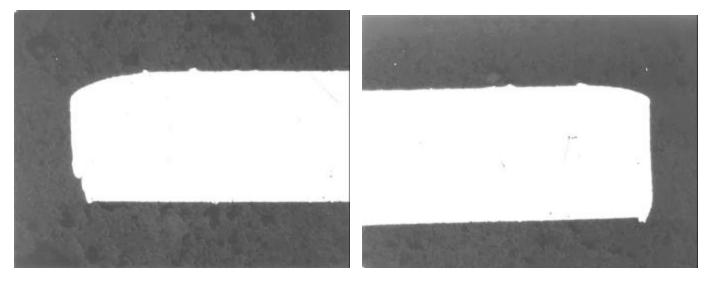


Figure 8. Cross-section images of SN G05 showing portions of the die paddle embedded in the plastic molding material. Both images ≈ 200 X.

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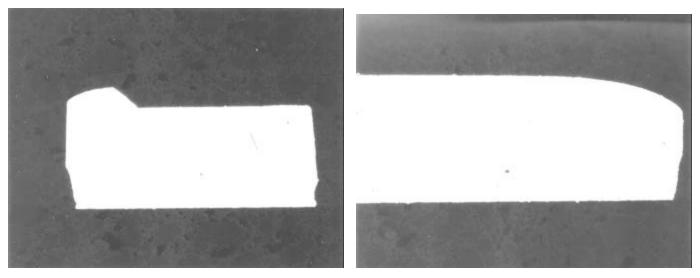


Figure 9. Cross-section images of SN G07. Left images shows lead frame finger embedded in plastic; right image shows a portion of the die paddle embedded in the plastic. Both images ≈ 200 X.

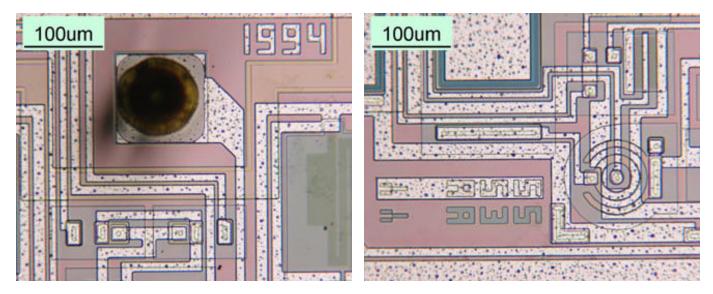


Figure 10. Optical micrograph images of SN H01 die show general device features.

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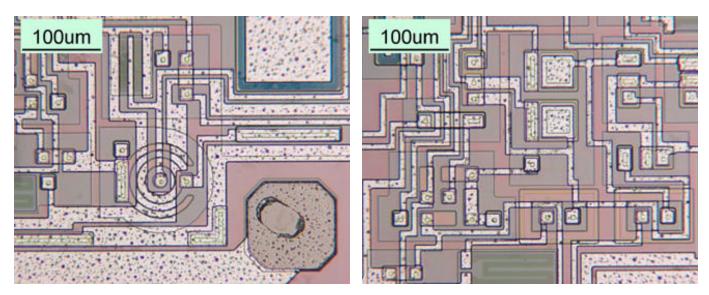


Figure 11. Optical micrograph images of SN H05 die.

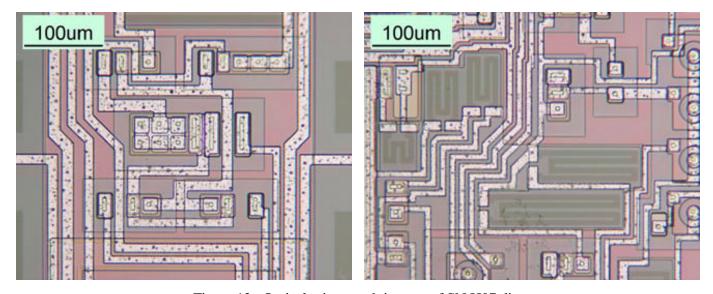


Figure 12. Optical micrograph images of SN H07 die.

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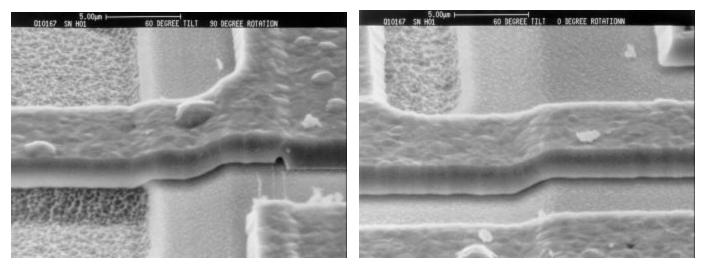


Figure 13. SEM micrograph shows excellent step coverage metallization on SN H01.

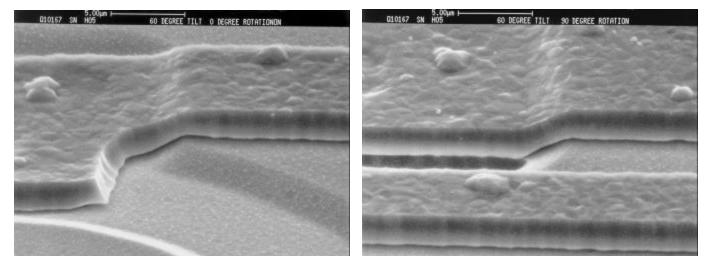


Figure 14. SEM micrographs of SN H05 show excellent step coverage.

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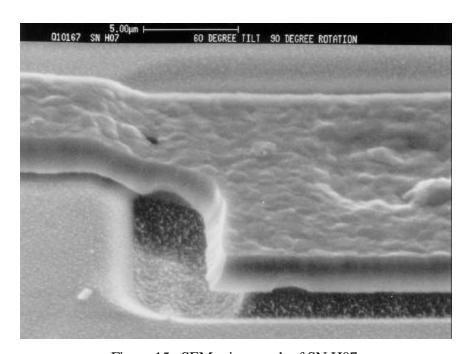


Figure 15. SEM micrograph of SN H07.

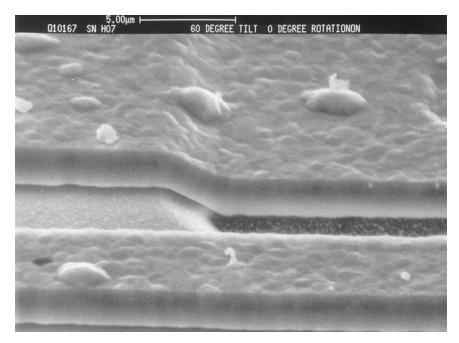


Figure 16. SEM micrograph of SN H07.